# **Hazard Warning and Car Direction Indicator**

# **Description**

Based on TEMIC's expertise in automotive flashers in bipolar technology, the U6432B is an improvement of the well known U6043B.

#### **Features**

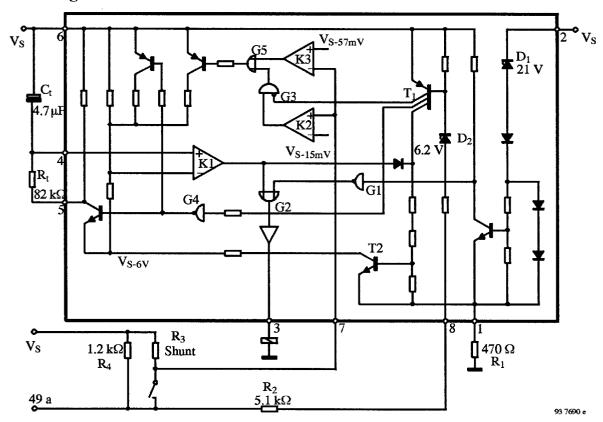
- Temperature and voltage compensated frequency
- Warning indication of lamp failure by means of frequency doubling only in direction mode
- Voltage dependence of the car indicator lamps also compensated for lamp failure
- Relay output with high current carrying capacity and low saturation voltage
- Load-dump protection

- Lamp load ≥ 1 W
- RF protected
- Extremely low stand by current of 10 μA

#### **Benefits**

- Damage and interference protection with a minimum of external components
- Low stand-by current allows battery operation

#### **Block Diagram**



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**Preliminary Information** 

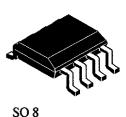
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### **Package Options**

8-pin dual inline plastic



8-pin SO plastic



### **Circuit Description**

The application circuit shows the operation of this IC as a car direction indicator signal generator. The flashing frequency is determined by the components  $R_t$  and  $C_t$ , and the frequency can be calculated from

$$f_1 \sim \frac{1}{R_1 + C + 1.5}$$
 (Hz)

where  $f_1$  is the frequency in normal flashing operation (basic frequency). The control frequency,  $f_2$ , is typically 2.2 times the value of  $f_1$  and is the frequency in the case of lamp failure. The bright periods for  $f_1$  and  $f_2$  are internally set in the IC and are 50% for  $f_1$  and 40% for  $f_2$ .

The resistors  $R_1$  and  $R_2$  are needed to protect the circuit against possible damage. An integrated protection circuit, together with these external resistors, limits the impulse current in the integrated circuit.

Protection in the case of battery reversal: The resistors  $R_1$ ,  $R_2$  and the relay coil limit the currents and the integrated circuit would not be damaged. To achieve a protection for continuous battery reversal, resistor  $R_1$  should be capable of 30 mA (0.5 W type).

A short circuit between indicator lamp (49a) and ground (31) can give rise to a voltage drop of about 4 V across the measuring resistance R<sub>3</sub>. In this case, the integrated circuit would not be damaged.

The use of the application circuit (see figure 1) ensures damage and interference protection consistent with VDE 0839 and load dump.

# Control signal threshold 1 (49 mV comparator)

The detection point for lamp failure can be calculated from the control signal threshold, typically 49 mV with  $V_S = 12$  V. With a measuring resistance of  $R_3 = 18$  m $\Omega$ , the frequency changeover is reached at a lamp load of 21 W +11.4 W. The variation of the control signal threshold supply voltage takes into account the PTC characteristic of filament lamps.

# Control signal threshold 2 (15 mV comparator)

A voltage drop at the shunt resistor R<sub>3</sub> between 49 mV and 15 mV let the flasher work in frequency doubling mode.

If the voltage drop falls of  $V_{R3MAX} = 15 \text{ mV}$  the frequency doubling is disabled.

This can be achieved either with a switch which by-passes the shunt resistor (e.g. a special hazard warning switch) or with a small lamp load.

The arrangement of the supply connections to Pin 2 and 6 must ensure that, on the connection PCB, the layer resistance from  $V_S$  to Pin 6 is lower than the one to Pin 2.

Flasher operation starts with a lamp load of  $P_L \ge 1 W$ .

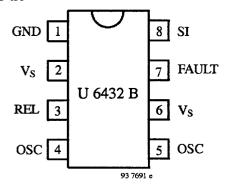
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# **U6432B-FP**

# Pin Out



# **Pin Description**

Pin	Symbol	Function
1	GND	IC ground
2	$V_{S}$	Supply voltage
3	REL	Relay driver
4	OSC	Oscillator
5	OSC	Oscillator
6	V <sub>S</sub>	Supply voltage
7	FAULT	Lamp failure detection
8	SI	Start input (49a)

# **Absolute Maximum Ratings**

Reference point pin 1

P	arameters	Symbol	Value	Unit	
Supply voltage	oly voltage Pin 2, 6		18	V	
Surge forward current					
$t_p = 0.1 \text{ ms}$	Pin 2, 6		1.5	Α	
$t_p = 300 \text{ ms}$	Pin 2, 6	I <sub>FSM</sub>	1.0	Α	
$t_p = 300 \text{ ms}$	Pin 8		30.0	mA	
Output current	Pin 3	I <sub>O</sub>	0.3	A	
Power dissipation					
$T_{amb} = 95^{\circ}C$	DIP 8		420		
	SO 8	P <sub>tot</sub>	340	mW	
$T_{amb} = 60^{\circ}C$	DIP 8		690		
	SO 8		560		
Junction temperature		T <sub>j</sub>	150	°C	
Ambient temperature range		T <sub>amb</sub>	-40 to +105	°C	
Storage temperature range	e	T <sub>stg</sub>	-55 to +125	°C	

#### **Electrical Characteristics**

 $T_{amb} = 25$ °C; typical values under normal operation in application circuit figure 1,  $V_S = 12$  V (Pin 2, 6); reference point ground (-31), unless otherwise specified.

Parameters	Test Conditions / Pins	Symbol	Min	Тур.	Max.	Unit
Supply voltage range	Pin 2, 6	$V_{S}$	9		16.5	V
Supply current, dark phase	Pin 2, 6	$I_S$		4.5	8	mA.
Supply current, stand-by	Pin 2, 6	$I_S$			10	μΑ
Supply current, bright phase	Pin 2, 6	I <sub>S</sub>		7.0	11	mA
Relay output, saturation voltage	$I_O = 150 \text{ mA},$ $V_S = 9 \text{ V}  \text{Pin } 3$	Vo			1.0	V
Relay output reverse current	Pin 3	Io			0.1	mA
Relay coil resistance		$R_{L}$	60			Ω
Start delay	first bright phase	t <sub>on</sub>			10	ms
Frequency determining resistor		$R_{t}$	6.8		510	kΩ
Frequency determining capacitor		G	·		47	μF
Frequency tolerance	normal flashing, basic frequency f <sub>1</sub> not including the tolerances of the external components R <sub>t</sub> and C <sub>t</sub>	$\Delta \mathbf{f}_1$	-5		+5	%
Bright period	basic frequency $f_1$ , $V_S = 9-15 \text{ V}$	$\Delta \mathbf{f}_1$	47		53	%
Bright period basic frequency $f_1$ , $V_S = 9-15 \text{ V}$		$\Delta \mathbf{f}_1$	47		53	%
Bright period	control frequency $f_2$ , $V_S = 9-15 \text{ V}$	$\Delta f_2$	37		45	%
Frequency increase	lamp failure, $V_S = 9-15 \text{ V}$	$f_2$	2.15 f <sub>1</sub>		2.3	$\mathbf{f_1}$
Control signal threshold 1	$V_S = 15 V$ $V_S = 9 V$ $V_S = 12 V$ Pin 7	V <sub>R3</sub>	50 43 47	53 45 49	57 47 51	mV
Control signal threshold 2		$V_{R3}$			15	mV
Resistance between 49a to ground for standby		$R_{p}$			5	kΩ
Lamp load		$P_{\rm L}$	1			W

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# **Dimensions in mm**

